



Switching Applications (with Bias Resistance)

Applications

· Switching circuits, inverter circuits, interface circuits, driver circuits.

Features

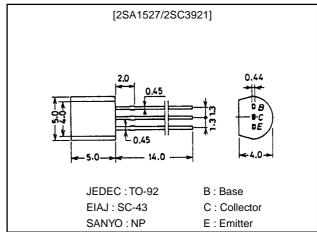
· On-chip bias resistance : R1=4.7k Ω , R2=4.7k Ω .

· Large current capacity : I_C=500mA.

Package Dimensions

unit:mm

2003A



(): 2SA1527

Specifications

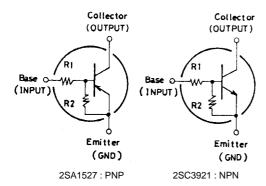
Absolute Maximum Ratings at Ta = 25°C

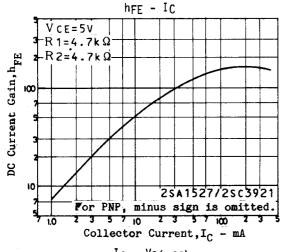
| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|------------|-------------|------|
| Collector-to-Base Voltage | V _{CBO} | | (–)50 | V |
| Collector-to-Emitter Voltage | VCEO | | (–)50 | V |
| Emitter-to-Base Voltage | V _{EBO} | | (–)6 | V |
| Collector Current | IC | | (–)500 | mA |
| Collector Current (Pulse) | I _{CP} | | (–)800 | mA |
| Collector Dissipation | PC | | 600 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

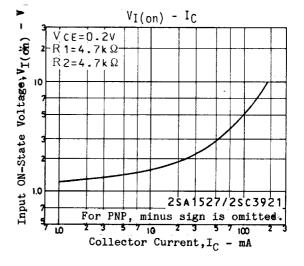
Electrical Characteristics at Ta = 25°C

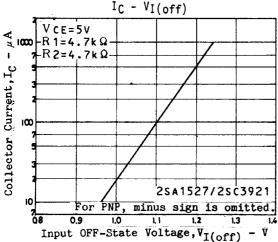
| Parameter | Symbol | Conditions | | Ratings | | |
|---|----------------------|---|--------|---------|--------|------|
| | | | min | typ | max | Unit |
| Collector Cutoff Current | I _{CBO} | V _{CB} =(-)40V, I _E =0 | | | (-)0.1 | μA |
| | ICEO | V _{CE} =(-)40V, I _B =0 | | | (-)0.5 | μΑ |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =(-)5V, I _C =0 | (-)410 | (-)532 | (-)760 | μΑ |
| DC Current Gain | h _{FE} | V _{CE} =(-)5V, I _C =(-)20mA | 50 | | | |
| Gain-Bandwidth Product | f _T | V _{CE} =(-)10V, I _C =(-)5mA | | 250 | | MHz |
| | | | | (200) | | MHz |
| Output Capacitance | C _{ob} | V _{CB} =(-)10V, f=1MHz | | 3.7 | | pF |
| | | | | (5.5) | | pF |
| Collector-to-Emitter Saturation Voltage | V _{CE(sat)} | I _C =(-)40mA, I _B =(-)2mA | | (–)0.1 | (-)0.3 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =(-)10μA, I _E =0 | (-)50 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CEO | I _C =(-)100μA, R _{BE} =∞ | (-)50 | | | V |
| Input OFF-State Voltage | V _{I(off)} | V _{CE} =(-)5V, I _C =(-)100μA | (-)0.8 | (–)1.1 | (–)1.5 | V |
| Input ON-State Voltage | V _{I(on)} | V _{CE} =(-)0.2V, I _C =(-)20mA | (-)1.0 | (–)1.9 | (-)4.0 | V |
| Input Resistance | R1 | | 3.3 | 4.7 | 6.1 | kΩ |
| Resistance Ratio | R1/R2 | | 0.9 | 1.0 | 1.1 | |

Electrical Connection









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